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Docket No.: 067161-0138

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 20277

Tsukasa OOISHI : Confirmation Number: 5634

Application No.: 10/777,069 : Group Art Unit: 2824

Filed: February 13, 2004 : Examiner: NGUYEN, VAN THU T

For: THIN FILM MAGNETIC MEMORY DEVICE FOR WRITING DATA OF A PLURALITY

OF BITS IN PARALLEL

INFORMATION DISCLOSURE STATEMENT

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

Each non-English language reference was first cited in a corresponding foreign application search report or office action and its relevance discussed therein. A copy of the

10/777,069

foreign search report or office action, together with an English language version thereof, is attached for the Examiner's information.

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

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Facsimile: 202.756.8087 **Date: July 5, 2005**

Please recognize our Customer No. 20277 as our correspondence address.

INFORMATION DISCLOSURE					ATTY. DOCKET NO.		SERIAL NO.			
CITATION IN AN					067161-0138		10/777,0)69		
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					APPLICANT Tsukasa OOISHI					
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(PTO-1449)						February 13, 2004 2824				
TRADEMAR	<u></u>			S PATEN	T DOCUMENTS					
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.